Erratum: Strongly three-dimensional electronic structure and Fermi surfaces of $\text{SrFe}_2(\text{As}_{0.65}\text{P}_{0.35})_2$: Comparison with $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$ [Phys. Rev. B **89, 184513 (2014)]**

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In Sec. III of the original paper, the carrier numbers are estimated incorrectly. The fourth paragraph of Sec. III should be replaced by “The carrier number per unit cell per spin calculated from the FS volumes of Sr122P are $n_\alpha = 0.005$, $n_\beta = 0.05$, $n_\gamma = 0.09$ (hole FSs), $n_\delta = 0.05$, and $n_\epsilon = 0.02$ (electron FSs), respectively. Although Sr122P is an isovalently substituted material, the total hole number $n_h = 0.15$ estimated from ARPES is larger than the total electron number $n_e = 0.07$.”

The present Erratum does not affect the conclusions of the original paper.